



ON Semiconductor®

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MCH6661

N-Channel Power MOSFET 30V, 1.8A, 188mΩ, Dual MCPH6

Features

- ON-resistance Nch : $R_{DS(on)1}=145m\Omega$ (typ.)
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	V_{DSS}		30	V
Gate to Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		1.8	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	7.2	A
Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	0.8	W
Junction Temperature	T_J		150	°C
Storage Temperature Purposes,	T_{stg}		-55 to +150	°C
Lead Temperature for Soldering Purposes, 3mm from Case for 10 Seconds	T_L		260	°C

This product is designed to "ESD immunity < 200V**", so please take care when handling.

* Machine Model

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	156.3	°C/W

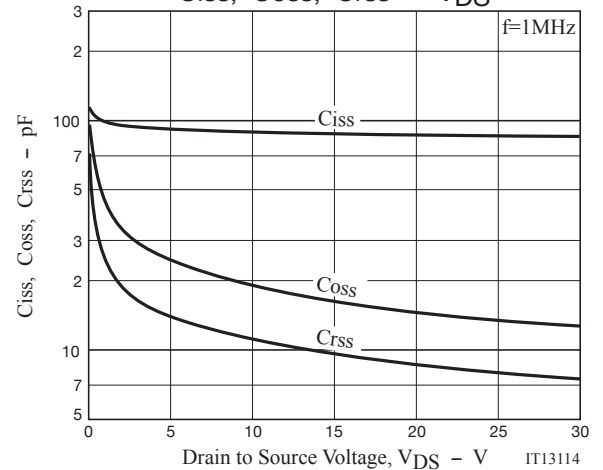
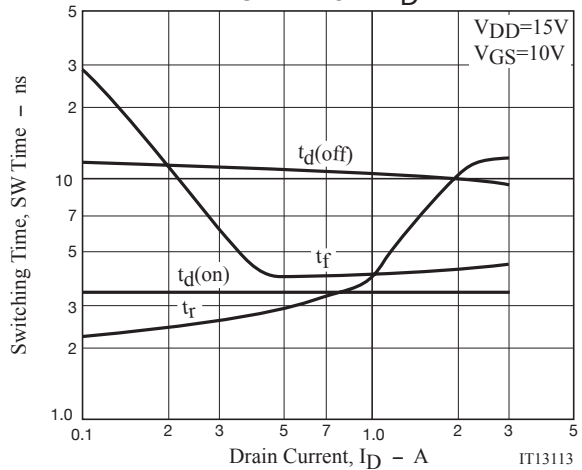
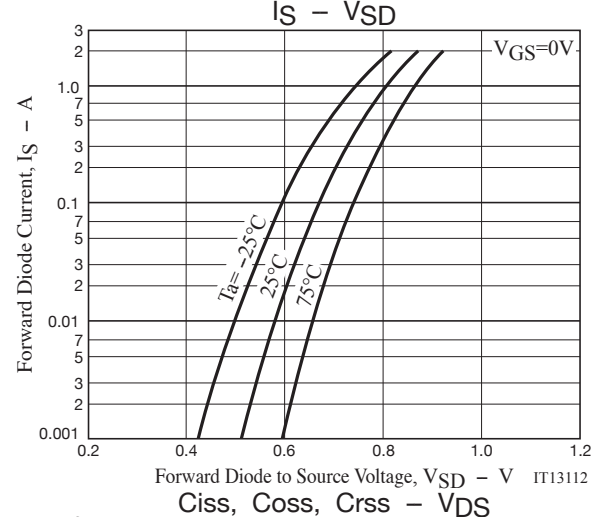
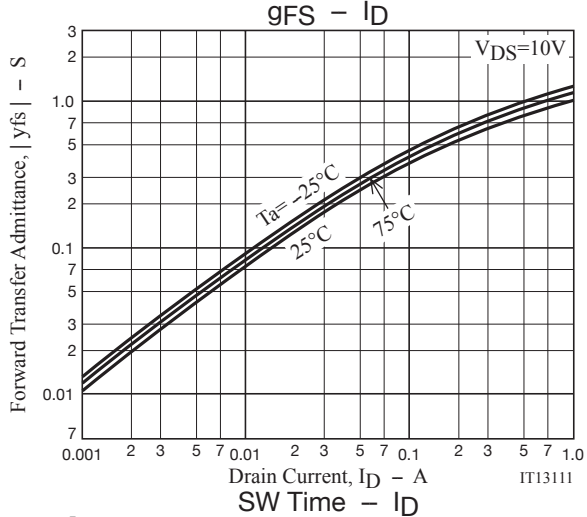
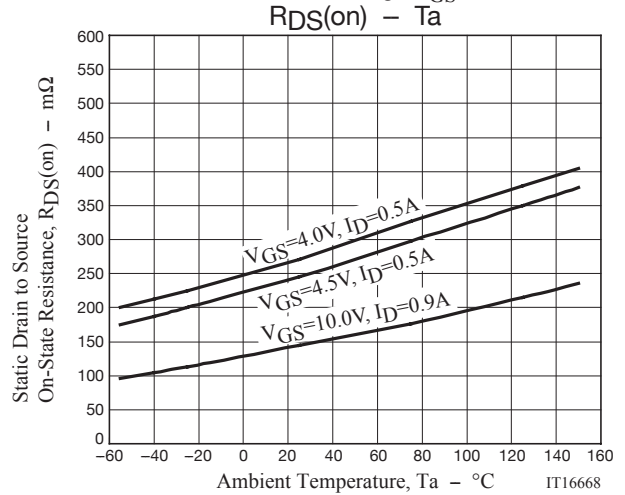
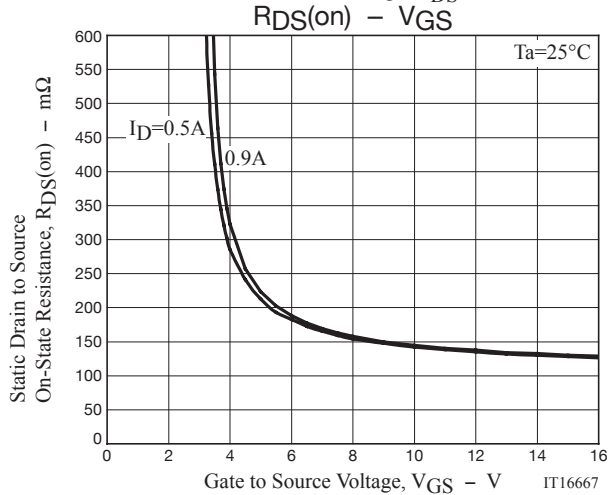
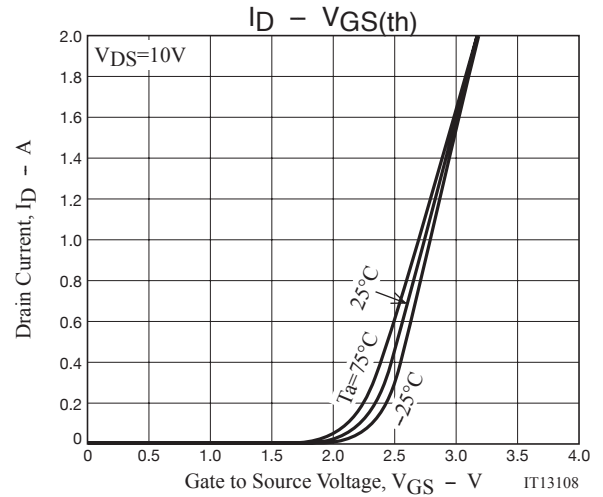
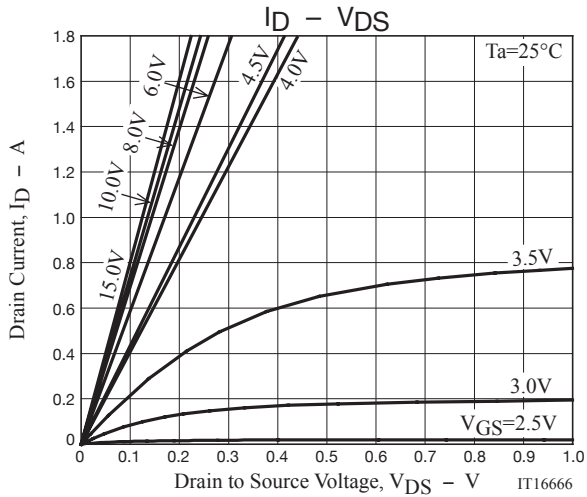
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

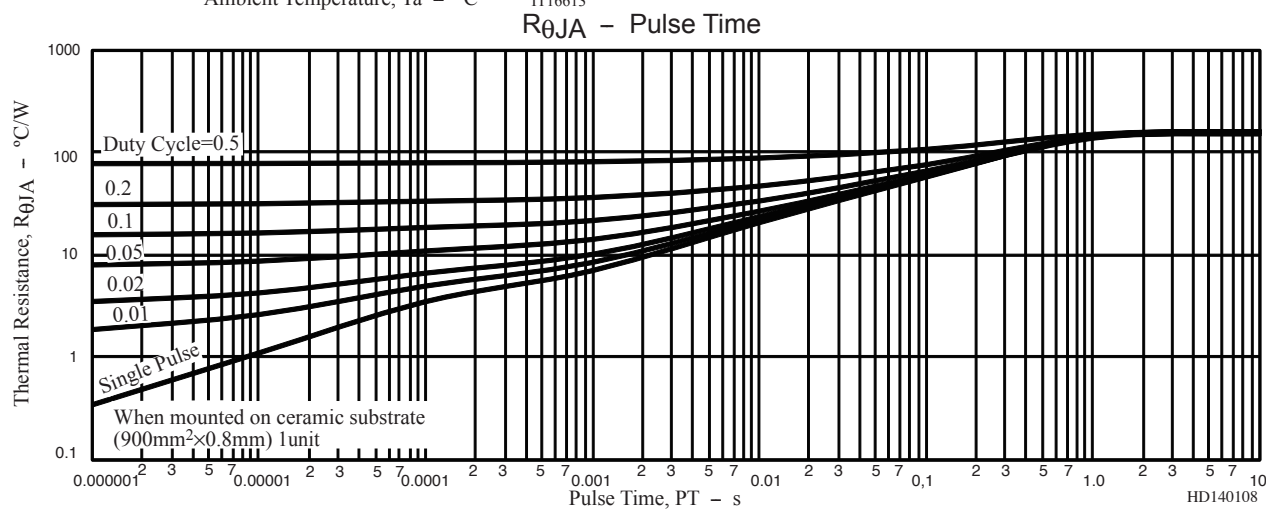
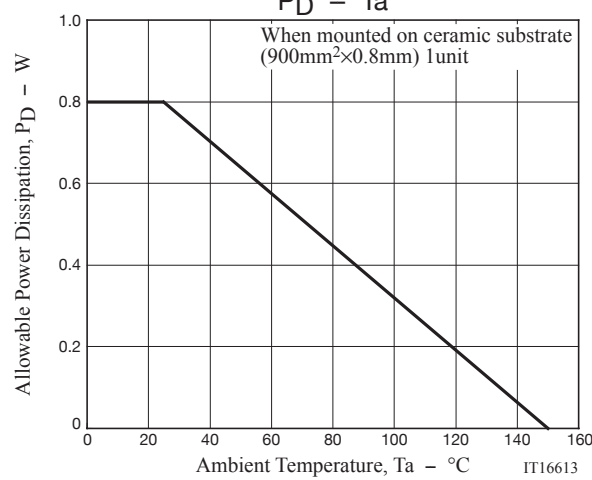
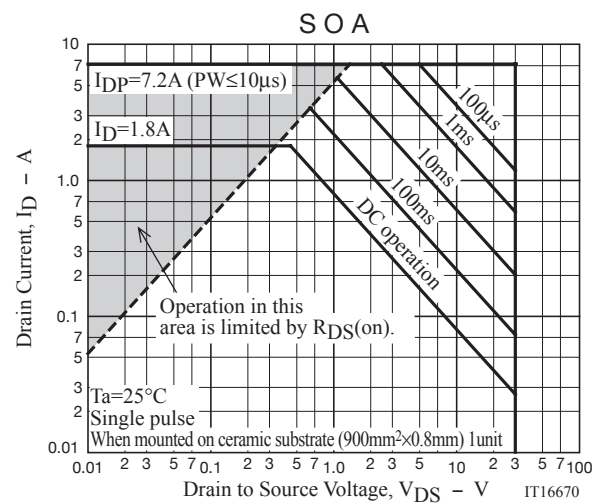
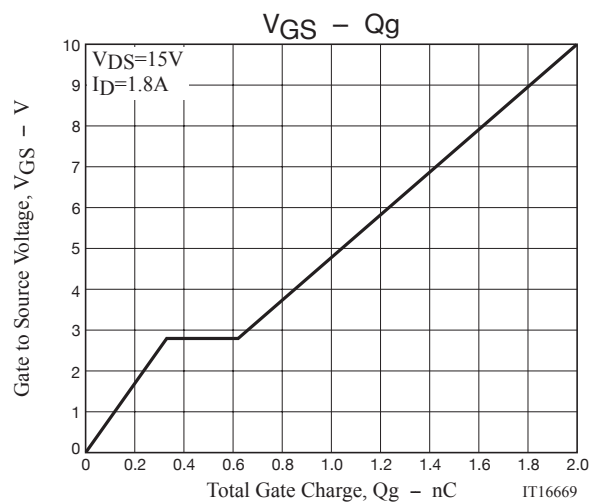
Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA$, $V_{GS}=0V$	30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V$, $V_{GS}=0V$			1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V$, $V_{DS}=0V$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=10V$, $I_D=1mA$	1.2		2.6	V
Forward Transconductance	g_{FS}	$V_{DS}=10V$, $I_D=0.9A$		1.1		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D=0.9A$, $V_{GS}=10V$		145	188	$m\Omega$
	$R_{DS(on)2}$	$I_D=0.5A$, $V_{GS}=4.5V$		245	343	$m\Omega$
	$R_{DS(on)3}$	$I_D=0.5A$, $V_{GS}=4V$		270	378	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=10V$, $f=1MHz$		88		pF
Output Capacitance	C_{oss}			19		pF
Reverse Transfer Capacitance	C_{rss}			11		pF
Turn-ON Delay Time	$t_{d(on)}$			3.4		ns
Rise Time	t_r	See specified Test Circuit.		3.6		ns
Turn-OFF Delay Time	$t_{d(off)}$			10.5		ns
Fall Time	t_f			4.0		ns
Total Gate Charge	Q_g	$V_{DS}=15V$, $V_{GS}=10V$, $I_D=1.8A$		2.0		nC
Gate to Source Charge	Q_{gs}			0.33		nC
Gate to Drain "Miller" Charge	Q_{gd}			0.29		nC
Forward Diode Voltage	V_{SD}	$I_S=1.8A$, $V_{GS}=0V$		0.86	1.2	V

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.





MCH6661

Package Dimensions

MCH6661-TL-W

SC-88FL / MCPH6

CASE 419AS

ISSUE O

unit : mm

1:Source1

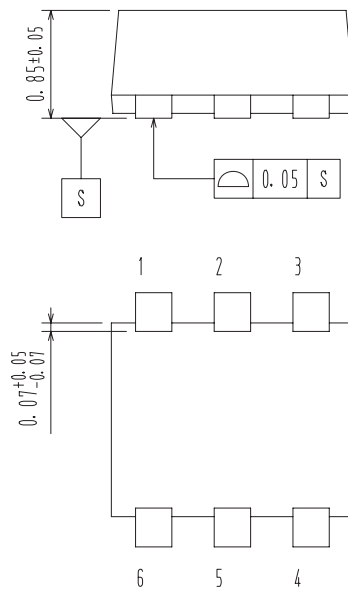
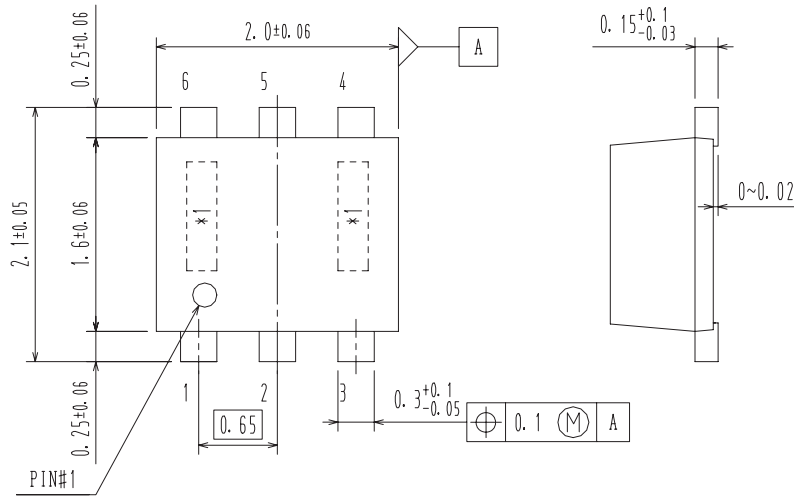
2:Gate1

3:Drain2

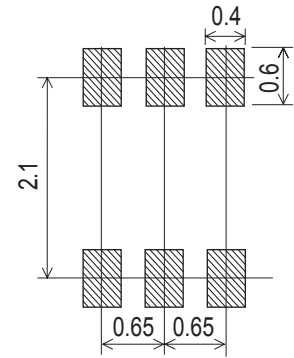
4:Source2

5:Gate2

6:Drain1



Recommended Soldering Footprint

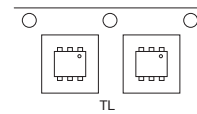


*1: Lot indication

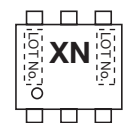
Ordering & Package Information

Device	Package	Shipping	note
MCH6661-TL-W	MCPH6, SC-88, SOT-363	3,000 pcs. / reel	Pb-Free and Halogen Free

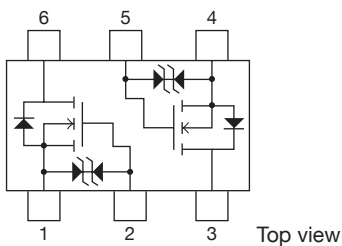
Packing Type: TL



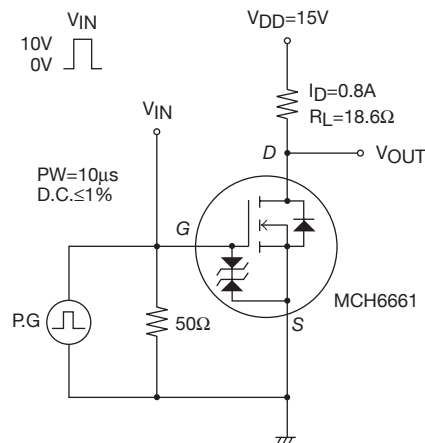
Marking



Electrical Connection



Switching Time Test Circuit



Note on usage : Since the MCH6661 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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